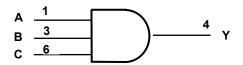


Pin Descriptions

Pin Name	Function
A	Data Input
GND	Ground
В	Data Input
Y	Data Output
Vcc	Supply Voltage
С	Data Input

Logic Diagram



Function Table

	Inputs					
Α	В	С	Y			
Н	Н	Н	Н			
L	Х	Х	L			
Х	L	Х	L			
Х	Х	L	L			

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
lıк	Input Clamp Current VI<0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
lo	Continuous output current	±50	mA
ICC MAX CONT	Continuous current through Vcc or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Symbol		Parameter	Min	Max	Unit
N/	Operating Voltage	Operating	1.65	5.5	V
Vcc	Operating Voltage	Data Retention Only	1.5		V
		V _{CC} = 1.65V to 1.95V	0.65 X V _{CC}		
		V _{CC} = 2.3V to 2.7V	1.7		V
VIH	High-Level Input Voltage	V _{CC} = 3V to 3.6V	2		v
		V _{CC} = 4.5V to 5.5V	0.7 X V _{CC}		
		V _{CC} = 1.65V to 1.95V		0.35 X V _{CC}	
		V _{CC} = 2.3V to 2.7V		0.7	V
VIL	Low-Level Input Voltage	V _{CC} = 3V to 3.6V		0.8	v
		V _{CC} = 4.5V to 5.5V		0.3 X V _{CC}	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 1.65V		-4	
		V _{CC} = 2.3V		-8	
I _{OH}	High-Level Output Current	V _{CC} = 3V		-16	mA
		$v_{\rm CC} = 3v$		-24	
		$V_{CC} = 4.5V$		-32	
		V _{CC} = 1.65V		4	
		$V_{CC} = 2.3V$		8	
I _{OL}	Low-Level Output Current	V _{CC} = 3V		16	mA
		V(C) = 3 V		24	
		V _{CC} = 4.5V		32	
	Innut Transition Dise or 5-"	V_{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V		20	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V
		$V_{CC} = 5V \pm 0.5V$		5	
TA	Operating Free-Air Temperature		-40	+125	°C

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Note: 5. Unused inputs should be held at V_{CC} or Ground.



Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
		I _{OH} = -100μA	1.65V to 5.5V	V _{CC} – 0.1			
		I _{OH} = -4mA	1.65V	1.2			
		I _{OH} = -8mA	2.3V	1.9			V
Vон	High-Level Output Voltage	I _{OH} = -16mA	2) (2.4			v
		I _{OH} = -24mA	3V	2.3			
		I _{OH} = -32mA	4.5V	3.8			
		I _{OL} = 100μA	1.65V to 5.5V			0.1	
		I _{OL} = 4mA	1.65V			0.45	
		I _{OL} = 8mA	2.3V			0.3	V
V _{OL}	Low-Level Output Voltage	I _{OL} = 16mA	2) (0.4	v
		I _{OL} = 24mA	3V			0.55	
		I _{OL} = 32mA	4.5V			0.55	
li -	Input Current	V _I = 5.5 V or GND	0 to 5.5V			± 5	μA
I _{OFF}	Power Down Leakage Current	V_1 or V_0 = 5.5V	0			± 10	μA
Icc	Supply Current	$V_{I} = 5.5V \text{ of GND}, I_{O} = 0$	1.65V to 5.5V			10	μA
ΔI _{CC}	Additional Supply Current	Input at V _{CC} –0.6V	3V to 5.5V			500	μA

Electrical Characteristics $T_A = -40^{\circ}C$ to +85°C (All typical values are at $V_{CC} = 3.3V$, $T_A = +25^{\circ}C$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
		I _{OH} = -100μA	1.65V to 5.5V	V _{CC} – 0.1			
		I _{OH} = -4mA	1.65V	0.95			
V	High-Level Output Voltage	I _{OH} = -8mA	2.3V	1.7			V
V _{OH}		I _{OH} = -16mA	2)/	1.9			v
	I _{OH} = -24mA		- 3V	2.0			
		I _{OH} = -32mA	4.5V	3.4			
		I _{OL} = 100μA	1.65V to 5.5V			0.1	
		I _{OL} = 4mA	1.65V			0.70	
	Low Lovel Output Voltage	I _{OL} = 8mA	2.3V			0.45	V
V _{OL}	Low-Level Output Voltage	I _{OL} = 16mA	- 3V			0.60	v
		I _{OL} = 24mA	- 3V			0.80	
		I _{OL} = 32mA	4.5V			0.80	
II.	Input Current	V _I = 5.5 V or GND	0 to 5.5V			± 20	μA
I _{OFF}	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O}$ = 5.5V	0			± 20	μA
Icc	Supply Current	$V_{\rm I}$ = 5.5V of GND, $I_{\rm O}$ = 0	1.65V to 5.5V			40	μA
Δl _{CC}	Additional Supply Current	Input at V _{CC} –0.6 V	3V to 5.5V			5000	μA



Package Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Cı	Input Capacitance	$V_I = V_{CC} - or GND$	3.3		3.5		pF
		SOT26			204		
0	θ _{JA} Thermal Resistance Junction- to-Ambient	SOT363	(Niete 6)		371		°C/W
θJA		X2-DFN1410-6	(Note 6)		430		0/11
		X2-DFN1010-6			510		
		SOT26			52		
0	JC to-Case	SOT363	(Nata C)		143		°C/W
θ_{JC}		X2-DFN1410-6	(Note 6)		190		C/vv
		X2-DFN1010-6	7		250		1

Note: 6. Test condition for SOT26, SOT363, X2-DFN1410-6 and X2-DFN1010-6 : Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

T _A = -40°C to +88	5°C, C _L = 18	5pF (see Figure	1)								
Parameter	From (Input)	TO (OUTPUT)		$v_{cc} = 1.8V$ $V_{cc} = 2.5V$ $V_{cc} = 3.3V$ $\pm 0.15V$ $\pm 0.2V$ $\pm 0.3V$					Unit		
	(input)	(001201)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Any	Y	1.0	15.2	0.7	5.6	0.7	4.1	0.7	3.1	ns

T_A = -40°C to +85°C, C_L = 30 or 50pF (see Figure 2)

Parameter	From (Input)	TO (OUTPUT)	V _{CC} = 1.8V ± 0.15V			: 2.5V .2V	V _{CC} = 3.3V ± 0.3V		V _{CC} ± 0	= 5V).5V	Unit
		(001101)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Any	Y	1.0	17.2	0.7	6.2	0.7	4.9	0.7	3.5	ns

T_A = -40°C to +125°C, C_L = 15 pF (see Figure 1)

Parameter	From (Input)		V _{CC} = ± 0.	1.8V 15V	V _{CC} = 2.5V ± 0.2V		V _{CC} = 3.3V V _{CC} = 5V ± 0.3V ± 0.5V			Unit	
			Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Any	Y	1.0	18.3	0.7	6.7	0.7	4.9	0.7	3.7	ns

T_A = -40°C to +125°C, C_L = 30 or 50pF (see Figure 2)

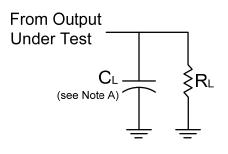
Parameter	From (Input)		V _{CC} = 1.8V ± 0.15V		V _{CC} = ± 0	: 2.5V .2V	V _{CC} = 3.3V ± 0.3V			= 5V 0.5V	Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Any	Y	1.0	20.7	0.7	7.5	0.7	5.9	0.7	4.2	ns



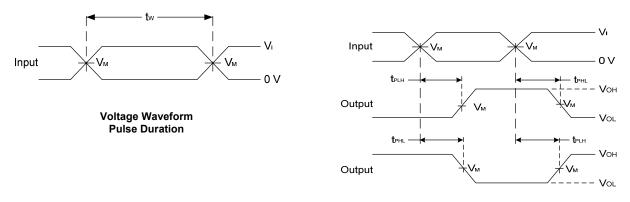
Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter		V _{CC} = 1.8V Typ	V _{CC} = 2.5V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
C _{pd}	Power dissipation capacitance	f = 10 MHz	17	18	19	22	pF

Parameter Measurement Information



N N	Inputs		X	0	
V _{cc}	VI	t _r /t _f	V _M	CL	RL
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1MΩ
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

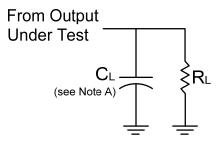
Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

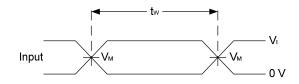
Figure 1 Load Circuit and Voltage Waveforms



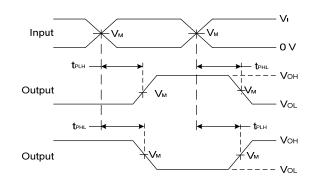
Parameter Measurement Information (cont.)



N N	Inj	outs	V	<u> </u>	
V _{cc}	VI	t _r /t _f	V _M	CL	RL
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1kΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	Vcc	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

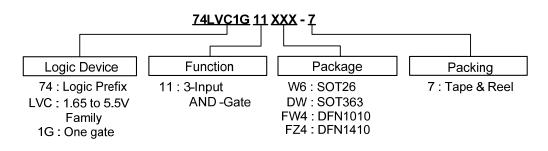
Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 2 Load Circuit and Voltage Waveforms



Ordering Information

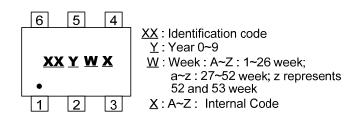


Part Number	Packara Cada Pac	Packaging	7" Tape and Reel	
Part Number	Package Code	(Note 7)	Quantity	Part Number Suffix
74LVC1G11W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC1G11DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC1G11FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74LVC1G11FZ4-7	FW4	X2-DFN1410-6	5000/Tape & Reel	-7

Note: 7. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SOT26, SOT363



Part Number	Package	Identification Code
74LVC1G11W6	SOT26	TV
74LVC1G11DW	SOT363	TV

(2) X2-DFN1010-6, X2-DFN1410-6

(Top View)	
XX	XX:Ide Y:Ye
YWX	
•	a~
	52

. . .

(: Identification Code 7 : Year : 0~9 <u>V</u>: Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week

 \underline{X} : A~Z : Internal code

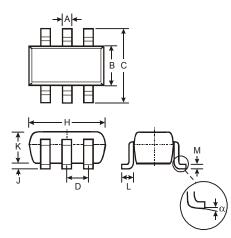
Part Number	Package	Identification Code
74LVC1G11FW4	X2-DFN1010-6	TV
74LVC1G11FZ4	X2-DFN1410-6	TV



Package Outline Dimensions (All dimensions in mm.)

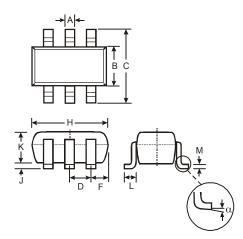
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SOT26



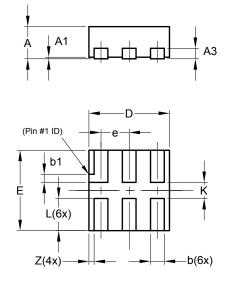
	SOT26				
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
в	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	_		0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
κ	1.00	1.30	1.10		
L	0.35	0.55	0.40		
Μ	0.10	0.20	0.15		
α	0°	8°	_		
All D	imensi	ons in	mm		

(2) Package Type: SOT363



	SOT363			
Dim	Min	Max		
Α	0.10	0.30		
В	1.15	1.35		
С	2.00	2.20		
D	0.65	Тур		
F	0.40	0.45		
Н	1.80	2.20		
J	0	0.10		
ĸ	0.90	1.00		
L	0.25	0.40		
М	0.10	0.22		
α	0°	8°		
All Di	mensions	in mm		

(3) Package Type: DFN1010



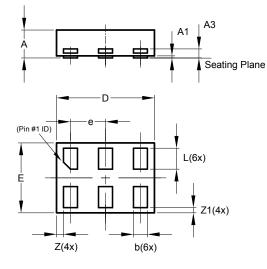
	X2-DFN1010-6				
Dim	Min	Мах	Тур		
Α		0.40	0.39		
A1	0.00	0.05	0.02		
A3			0.13		
b	0.14	0.20	0.17		
b1	0.05	0.15	0.10		
D	0.95	1.05	1.00		
Е	0.95	1.05	1.00		
е			0.35		
L	0.35	0.45	0.40		
κ	0.15				
Z			0.065		
All	Dimens	ions in	mm		



Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(4) Package Type X2-DFN1410-6



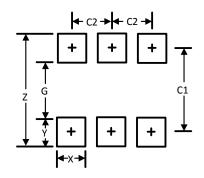
	X2-DFN1410-6				
Dim	Min	Max	Тур		
Α	_	0.40	0.39		
A1	0.00	0.05	0.02		
A3	_		0.13		
b	0.15	0.25	0.20		
D	1.35	1.45	1.40		
Е	0.95	1.05	1.00		
е	_		0.50		
L	0.25	0.35	0.30		
Z			0.10		
Z1	0.045	0.105	0.075		
All	All Dimensions in mm				



Suggested Pad Layout (All dimensions in mm.)

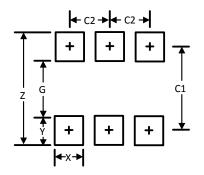
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT26



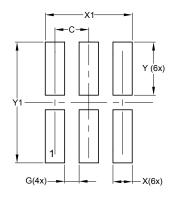
Dimensions	Value (in mm)
Z	3.20
G	1.60
х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT363



Dimensions Value (in mm) Z 2.5 G 1.3 X 0.42 Y 0.6 C1 1.9 C2 0.65

(3) Package Type X2-DFN1010-6



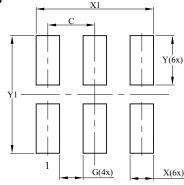
Dimensions	Value (in mm)
С	0.350
G	0.150
Х	0.200
X1	0.900
Y	0.550
Y1	1.250



Suggested Pad Layout (cont.)

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(4) Package Type: X2-DFN1410-6



Dimensions	Value (in mm)
С	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

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